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W e calculate the charge sensitivity of a recently dem onstrated device where the Josephson inductance of a single Cooper-pair transistor is measured. We nd that the intrinsic lim it to detector perform ance is set by oscillator quantum noise. Sensitivity better than 10⁶ = Hz is possible with a high Q-value 10³, or using a SQUID amplier. The model is compared to experiment, where charge sensitivity 3 10⁵ = Hz and bandwidth 100 MHz are achieved.

PACS num bers: 85.35.Gv, 85.25.Cp, 73.23.Hk

R em arkable quantum operations have been dem onstrated in the solid state [1, 2, 3]. As exotic quantum m easurem ents known in quantum optics are becoming adopted for electronic circuits [4], sensitive and desirably non-destructive m easurem ent of the electric charge is becoming even m ore im portant.

A new type of fast electrom eter, the Inductive Single-E lectron Transistor (L-SET) was demonstrated recently [5]. Its operation is based on gate charge dependence of the Josephson inductance of a single Cooper-pair transistor (SCPT). As compared to the fam ous rf-SET [6], where a high-frequency electrom eter is built using the control of single-electron dissipation, the L-SET has several orders of m agnitude lower dissipation due to the lack of shot noise, and hence also potentially lower backaction.

Charge sensitivity of the sequential tunneling SET has been thoroughly analyzed. However, little attention has been paid on detector performance of the SCPT, probably because no real electrom eter based on SCPT had been demonstrated until invention of the L-SET. Som e claims have been presented [5, 7] that performance of SCPT in the L-SET setup could exped the shot-noise limit of the rf-SET [8], s_q ' 10 ⁶ \rightleftharpoons Hz, but no accurate calculations have appeared.

In this letter we carry out a sensitivity analysis for L-SET in the regime of linear response. We not that (neglecting 1=f background charge noise) the intrinsic lim it to detector sensitivity is set, unlike by shot noise of electron tunneling in a norm al SET, by zero-point uctuations [9].

A SCPT has the single-junction Josephson energy E_J, and the total charging energy E_C = e^2 =(2C), where C is the total capacitance of the island. At the lowest energy band the energy is E₀, the elective Josephson energy is E_J = e^2 E₀(q;')= $e^{\prime 2}$, and the elective Josephson inductance is L_J = $(2 = _0)^2$ (E_J)¹. These have a substantial dependence on the (reduced) gate charge q = C_gV_g=e if E_J=E_C < 1. Here, ' is the phase across the SCPT.W ith a shunting capacitance C, SCPT forms a parallel oscillator. We further shunt the oscillator, m ainly for practical convenience, by an inductor L ' L_J. Hence we have the resonator as shown in F ig.1, with the plasm a frequency f_p = $!_p = (2) = 1 = (2) (L_{tot}C)^{1=2}$

1 GHz, where $L_{\text{tot}} = L \text{ k} L_{\text{J}}$.

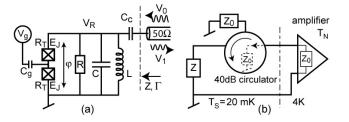


FIG.1: The L-SET resonator (a), and its equivalent circuit (impedance Z) coupled to cabling (b).

The coupling capacitor, typically C_c C, allows, in principle, for an arbitrarily high loaded quality factor Q_L . If directly coupled to feedline, $Q_L = Z_0$ C = L_{tot} 1, which is clearly intolerable. W ith a coupling capacitor, how ever, $Q_L = 1=2Q_i$ in the optimal case (as shown later) of critical coupling Z = Z_0 (Q_i is the internal Q-value). The resistor R is a model component for internal losses.

W e consider only the linear regim e, where the detector works by converting charge to resonant frequency. W e do not m odel the "anharm onic" operation m ode [5] where ' oscillates in the nonlinear regim e of the Josephson potential, yielding in fact better sensitivities in experim ent.

Im pedance of the L-SET circuit as illustrated in Fig.1 is

$$Z = \frac{1}{i!C_{c}} + i!C + \frac{1}{i!L} + \frac{1}{i!L_{J}} + \frac{1}{R}^{-1} : (1)$$

The circuit is probed by measuring the voltage rejection coecient = $j j exp(iarg()) = (Z Z_0) = (Z + Z_0)$ to an incoming voltage wave of amplitude V_0 . The rejected wave amplitude is $V_1 = j j V_0$. Here, $Z_0 = 50$ is the wave impedance of coaxial lines.

Spectral density of noise power at the output of the 1st stage ampli er, referred to ampli er input, is $k_B T_N$, where the e ective temperature T_N is due to ampli er noise and sample noise: $T_N = T_N + T_S$. Sample is supposed to be critically coupled, and hence its noise is like that of a 50 resistor at the temperature T_S

(note that the Josephson e ect is a system ground state property and hence it contributes no noise). Typically, $k_B T_S < h!_p$, and thus sample noise is already in the quantum lim it.

Noise of contemporary rf-ampliers, however, remains far from the quantum limit, i.e., $T_{\rm N}$ $T_{\rm S}$. The best demonstrated SQUID-based rf-ampliers have reached $T_{\rm N}$ 100 200 mK [10]. Therefore, added noise from the sample can be safely ignored when analyzing detector performance.

Charge sensitivity for am plitude modulation (AM) of the rfSET was calculated in detail in Ref. [11] assuming detection of one sideband. It was assumed that the sensitivity is limited by general equivalent noise temperature similarly as here, and hence the formula applies as such:

$$s_{q} = \frac{p}{2k_{B}T_{N}} = V_{0}\frac{\varrho j j}{\varrho q} : \qquad (2)$$

In the linear regime, the best sensitivity of the L-SET is clearly at the largest acceptable value of V₀, where linearity still holds reasonably well. This is the case when an AC current of critical current peak value ow s through the SCPT, and the phase swing is p-p. Then, voltage across the SCPT, and resonator (later we discuss important quantum corrections to this expression), $V_R = \frac{1}{2}Z_R = (Z + Z_0) jV_0$ equals a universal critical voltage of a Josephson junction [12], $V_C = h! = (4e)' 3 V$ at $f_p = 1 \text{ GHz}$. Here, Z_R is impedance of the parallel resonator.

We decompose the derivative in Eq. (2) into term s due to the circuit and SCPT: $\frac{@j j}{@q} = \frac{@j j@!_P}{@!_P} \frac{@L_J}{@L_J} \frac{@L_J}{@q}$. We de ne a dimensionless transfer function $g^0 = (@L_J = @q)$ (e=L_{J0}) scaled according to minimum (w.r.t. gate) of L_J. The gate value which yields the maximum of g^0 , denoted g, is the optimum gate DC operation point of the charge detector. In what follows, L_J should be understood as its value at this point. With a given $E_J = E_C$ ratio, we compute the values of g and L_J numerically from the SCPT band structure (g is plotted in Fig. 4 in Ref. [5]). If $E_J = E_C$ 1, one can use the analytical result L_{J0} = 2 $\frac{2}{0} = (E_J)$.

W ith a general choice of param eters of the tank resonator, Eq. (2) needs to be evaluated num erically. How – ever, when the system is critically coupled, $Z = Z_0$, a simple analytical form ula can be derived. Num erical calculations of Eq. (2) over a large range of param eters show that the best sensitivity occurs when $Z = Z_0$. This is reasonable because it corresponds to the best power transfer. All the following results are for critical coupling. Later, we exam ine e ects of detuning from the optimum. Initially, we also suppose the oscillator is classical, i.e., its energy E $h!_p$.

Optimal value of the coupling capacitor is calculated using $Q_{L} = 1=2Q_{i}$, and we get $C_{c} = \frac{C}{C} = (!_{p}Q_{i}Z_{0})$.

Since it was assumed $Z = Z_0$, it holds that $Z_R = Z_0 + i = (!_p C_c)$. Voltage amplication by the resonator then becomes $V_R = V_0 \frac{p}{Q_i = (!_p Z_0 C)}$ which

holds for a reasonably large Q_i . We thus have $V_0 = h!_p^{3=2} \frac{p}{Z_0C} = (4e^p \overline{Q_i})$.

With $!_p = p(\underline{L}_{tot}C_p)^{1=2}$, we get immediately ($(!_p=(L_J)^{-1} = 2 C L_J^2)^{1=2}$, we get immediately ($(!_p=(L_J)^{-1} = 2 C L_J^2)^{-1}$, using the fact [13] that FW HM of the loaded resonance absorption dip at critical coupling is $!_p=(2Q_L)$, we get $(!_j=(!_p=2Q_L=!_p=Q_i=!_p)$.

Inserting these results into Eq. (2), we get expression for the AM charge sensitivity in the lim it the oscillator is classical:

$$s_{q} = \frac{8eL_{J}^{2}}{g} \frac{\frac{1}{L} + \frac{1}{L_{J}}p}{\frac{1}{L} + \frac{1}{L_{J}}} \frac{2k_{B}T_{N}}{2k_{B}T_{N}}}{ghL_{J0}!_{P}Q_{i}}$$
(3)

in units of [e=Hz]. C learly, the shunting inductor is best om itted, i.e., L ! 1 . The classical result, Eq. (3), in proves without lim it at low $E_J = E_C$.

We will now discuss quantum corrections to Eq. (3). A lthough spectral density of noise in the resonator is negligible in output, integrated phase uctuations even due to quantum noise can be large. Integrated phase noise in a high-Q oscillator is h ' $^{2}i = 2 {}^{2}hL_{tot}!_{p} = {}^{2}_{0}$ [14]. W hen h ' i exceeds the linear regime , which happens at high inductance (low E $_{\rm J}$ =E $_{\rm C}$), plasm a resonance "switches" into nonlinear regime, and the gain due to frequency m odulation vanishes. If L L_J , and f_p 1 GHz, we have ultimate limits of roughly $E_J = E_C$ 0:06, 0:02, for a SCPT m ade out of A lorNb, respectively. or

Even before this switching happens, quantum noise in the oscillator $E_Q=\frac{1}{2}h!_p$ has an adverse e ect because less energy can be supplied in the form of drive, that is, V_0 is smaller. This can be calculated in a sem iclassical way as follows. Energy of the oscillator is due to drive (E_D) and noise (we stay in the linear regime): E = ($_0\prime$)²=(8 $^2L_{tot}$) = E_D + E_Q = ($_0\prime_D$)²=(8 $^2L_{tot}$) + $\frac{1}{2}h!_p$, where the phases are in RM S, \prime is the total phase swing, and \prime_D is that due to drive. Solving for the latter, we get \prime_D = $\frac{\prime}{2}$ $\frac{4}{2}h!_pL_{tot}=\frac{2}{p^0}$. The optimal drive strength V_R = V_C corresponds to $\frac{2}{2}\prime$ = -2, and hence the maximum probing voltage V_0 is reduced by a factor = $\frac{1}{2}$ 32h!_pL_{tot}= $\frac{2}{0}$ due to quantum noise in the oscillator.

The optimal sensitivity is nally

$$s_{q}^{QL} = \frac{64^{p} \overline{2} e L_{J}^{2} p}{q \overline{h}_{0} L_{J} p} \overline{2k_{B} T_{N}}; \qquad (4)$$

which depends only weakly on operation frequency. We optimized Eq. (2) (replacing there V_0 by V_0) assuming similar tunnel junction properties as in the experiment, $E_J E_C = 1.8 \text{ K}^2$ (Al) and $E_J E_C = 10 \text{ K}^2$ (Nb). The results are plotted in Fig. 2 together with corresponding power dissipation ($V_C = 2$)²=R = ${}^{2}h^{2}!_{p} = (32e^2Q_iL_J)$.

The optimal sensitivity is reached around $E_J = E_C$ '0:1:::0:3, where the curves in Fig. 2 almost coincide Eq. (4). C_c should be chosen so that critical coupling

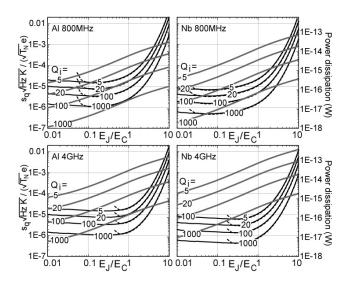


FIG. 2: Charge sensitivity of the L-SET optimized from Eq. (2) (black lines). The analytical result (Eq. (3) multiplied by 1), with L = 1, is shown with dashed lines. G ray lines are the corresponding power dissipation. All the graphs have the same scales, which are indicated for $s_{\rm q}$ (left) and dissipation (right). The curves are for di erent Q i as marked. All graphs have Z ' Z₀.

results. Typically also it should hold L L_J (see the analytical curve in Fig.2). However, sensitivity decreases only weakly if these values are detuned from their optimum (Fig.3).

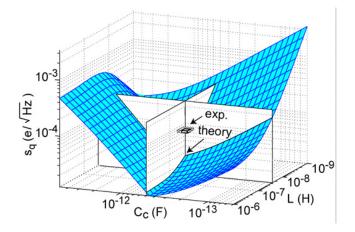


FIG.3: M easured charge sensitivity (box) compared to calculations. In experiment, C $_{\rm c}$ 0.5fF, and L 28nH.The graph shows also how the sensitivity would change as a function C $_{\rm c}$ and L according to the model.

By num erical investigation we found that readout of arg(), with mixer detection, o ers within accuracy of num erics the sam e num bers than the discussed AM (readout of j).

In experiment, we measured charge sensitivity for the following sample and resonator: R_T ' 11 k , E_J ' 0:7 K , E_C ' 2:6 K , E_J = E_C ' 0:3, Q_i ' 16, L ' 28 nH ,

C ' 12 pF, C_c ' 0.5 pF. In all sam ples so far, $Q_1 < 20$ which is presently not understood. The measurements were done as described in Ref. [5], with T_N 5 K [15]. We measured s_q = 7 $10^5 \rightleftharpoons$ Hz by AM at 1 MHz, while a prediction with the present parameters is s_q = 3 $10^5 \rightleftharpoons$ Hz (see also Fig. 3).

Theory and experiment thus agree reasonably. The somewhat lower sensitivity in experiment is likely to be due to external noise which forces a lower V_0 and also smoothes out the steepest modulation. Its origin is not clear. Also the 25% higher values of L_J than expected agree qualitatively with noise.

In the "anham onic" mode, we measured $s_q = 3$ 10⁵ \leftarrow Hz, with a usable bandwidth of about 100 M Hz ($s_q = 10^4 \leftarrow$ Hz at 100 M Hz). Considering both s_q and band, a perform ance comparable to the best rf-SETs [6, 16] has been reached with the L-SET, though here at more than two orders of magnitude lower power dissipation (10 fW).

In the linear regime, the power lost P from drive frequency m = 1 to higher harmonics is determined by the sum, form 2, of Josephson junction admittance components $j_{\rm M}' = 2J_m$ (2e=(h!)V₁). At the critical voltage V₁ = V_C, this amounts to Y =Y₁ = P =P₁ 30 %. Since charge sensitivity is proportional to square root of power, it thus decreases only 15% due to non-linearity. Further corrections due to slightly non-sinusoidal lowest band of the SCPT, as well as asymmetry due to manufacturing spread in junction resistance, we estimate as insigni cant.

Next we discuss non-adiabaticity. Interband Zener transitions might make the SCPT jump o from the supposed ground band 0. We make a worst case estimate by assuming that the drive is 2 p-p (partially due to noise). The probability to cross the minimum $_{\rm m}$ of band gap = E $_1$ E₀ is: P_z ' exp $_{\rm m}^2$ = (2hD '_), where we evaluate the dependence of the band gap on phase D = @ =@' at ' = =2.'_= 2! p is determined by the drive.

Zener tunneling is signi cant if it occurs su ciently often in comparison to 1 ! 0 relaxation. Threshold is when $P_Z = {}_{\#}=(2f_0)$, where ${}_{\#} > (1 \text{ s})^{-1}$ is the relaxation rate. Operation of the L-SET can thus be a ected above $P_Z = 10^4$.

Numerical calculations for P_z show that Zener tunneling is exponentially suppressed, at the L-SET optimal working point, in the interesting case of low $E_J = E_C$ [12]. This is because $_m$ becomes large and D small. For instance, if $E_J = 1$ K and $f_p = 1$ GHz, we got that Zener tunneling is insigni cant below $E_J = E_C$ 3. With $E_J = 0.5$ K and $f_p = 5$ GHz, the threshold is $E_J = E_C$ ' 1. We conclude that with su ciently high Q i and us-

ing a ampli er close to the quantum limit, even s_q 10⁷ $\stackrel{P}{=}$ Hz, order of magnitude better than the shotnoise limit of rf-SET, is intrinsically possible for the L-SET.So far, the sensitivity has been limited by Q_i < 20. Fruitful discussions with M. Feigelman, U.G avish, T. Heikkila, R. Lindell, H. Seppa are gratefully acknowledged. This work was supported by the A cadem y of Fin-

land and by the Large Scale Installation Program ULT I-3 of the European Union (contract HPR I-1999-CT-00050).

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